

SLD234VL

Index-Guided High Power AlGaAs Laser Diode

Description

The SLD234VL is a high power index-guided AlGaAs laser diode.

Features

- High power
- Low power consumption
- Low astigmatism
- Small package (\u00f65.6mm)

Applications

Pickups for optical discs

Structure

- AlGaAs quantum well-structured laser diode
- PIN photodiode for optical power output monitor

Recommended Operating Optical Power Output

50mW

Absolute Maximum Ratings (Tc = 25°C)

 Optical power output 	Po		50	mW	(CW)
			80	mW	(Pulse)
					Pulse period of 1µs or less
					Duty of 50% or less
 Reverse voltage 	VR	LD	2	V	
		PD	15	V	
 Operating temperature 	Topr	•	-10 to +60	°C	

• Storage temperature Tstg -40 to +85 °C

Connection Diagram



Pin Configuration



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Optical and Electrical Characteristics (Tc = 25°C)

Tc: Case temperature

lten	n	Symbol	Conditions	Min.	Тур.	Max.	Unit
Threshold curre	nt	lth	CW	15	20	30	mA
Operating curre	nt	Іор	CW, Po = 50mW	60	70	85	mA
Operating voltage	ge	Vop	CW, Po = 50mW	_	2.0	2.5	V
Oscillation wave	elength	λρ	CW, Po = 50mW	775	785	795	nm
Differential effic	iency	ηD	CW, Po = 50mW	0.8	1.0	1.3	mW/mA
Radiation	Parallel	θ//	CW, Po = 50mW	7	8.5	10	degree
angle Perpendicular		θ⊥	CW, Po = 50mW	19	22	27	degree
Astigmatism		As	CW, Po = 50mW	_		-6	μm
Monitor current		Im	CW, Po = 50mW, VR (PIN) = 5V	_	0.05	_	mA
Positional 4 accuracy	Anglo	Δφ//	CW, Po = 50mW	_	_	±2.0	degree
	Angle	$\Delta \phi \perp$	CW, Po = 50mW	_	_	±3.0	degree
	Position	ΔΧ, ΔΥ, ΔΖ		—	_	±80	μm

Package Outline Un

Unit: mm

M-260





SONY CODE	M-260		
EIAJ CODE			
JEDEC CODE		PACKAGE WEIGHT	0.3g